



Features:

- Isolated mounting base 3000V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving

Typical Applications:

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

V _{RRM} , V _{DRM}	Type & Outline	
600V	MTx330-06-413F3D	MFx330-06-413F3D
800V	MTx330-08-413F3D	MFx330-08-413F3D
1000V	MTx330-10-413F3D	MFx330-10-413F3D
1200V	MTx330-12-413F3D	MFx330-12-413F3D
1400V	MTx330-14-413F3D	MFx330-14-413F3D
1600V	MTx330-16-413F3D	MFx330-16-413F3D
1800V	MTx330-18-413F3D	MFx330-18-413F3D
1800V	MT330-18-413F3DG	

MTx stands for any type of **MTC, MTA, MTK**
 MFx stands for any type of **MFC, MFA, MFK**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{T(AV)}	Mean on-state current	180° half sine wave 50Hz Single side cooled, T _c =85°C	125			330	A
I _{T(RMS)}	RMS on-state current					518	A
I _{DRM} I _{RRM}	Repetitive peak current	at V _{DRM} at V _{RRM}	125			35	mA
I _{TSM}	Surge on-state current	V _R =60%V _{RRM} , t=10ms half sine,	125			9.1	kA
I ² t	I ² t for fusing coordination		125			414	10 ³ A ² s
V _{TO}	Threshold voltage		125			0.85	V
r _T	On-state slope resistance					0.53	mΩ
V _{TM}	Peak on-state voltage	I _{TM} =990A	25			1.58	V
dv/dt	Critical rate of rise of off-state voltage	V _{DM} =67%V _{DRM}	125			1000	V/μs
di/dt	Critical rate of rise of on-state current	Gate source 1.5A t _r ≤ 0.5μs Repetitive	125			200	A/μs
I _{GT}	Gate trigger current	V _A =12V, I _A =1A	25	30		180	mA
V _{GT}	Gate trigger voltage			0.7		2.5	V
I _H	Holding current			10		180	mA
I _L	Latching current					1000	mA
V _{GD}	Non-trigger gate voltage	V _{DM} =67%V _{DRM}	125			0.20	V
R _{th(j-c)}	Thermal resistance Junction to case	Single side cooled per chip				0.10	°C/W
R _{th(c-h)}	Thermal resistance case to heatsink	Single side cooled per chip				0.04	°C/W
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1min, I _{iso} : 1mA(MAX)		3000			V
F _m	Terminal connection torque(M8)			10.0		12.0	N·m
	Mounting torque(M6)			4.5		6.0	N·m
T _{vj}	Junction temperature			-40		125	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				770		g
Outline	413F3D						

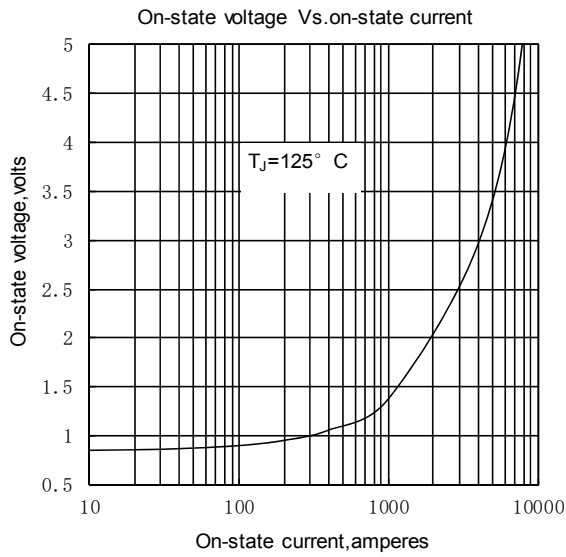


Fig.1

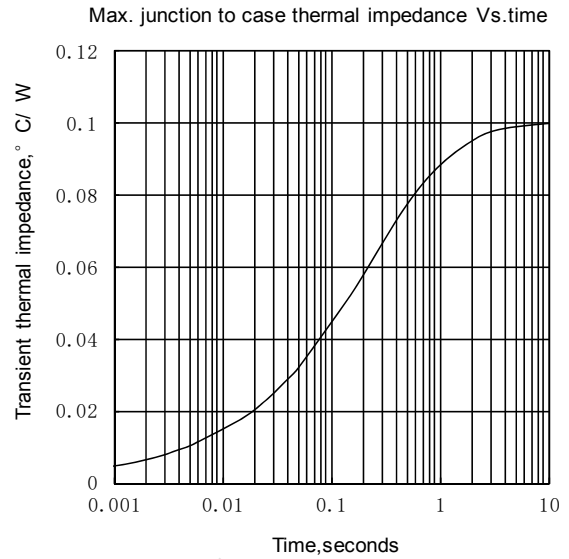


Fig.2

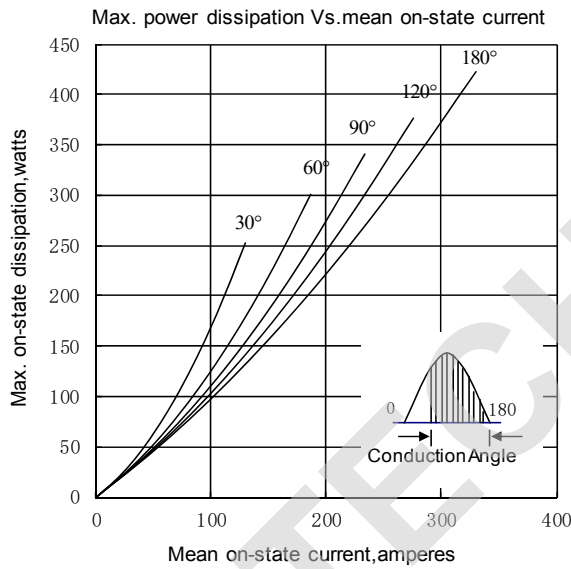


Fig.3

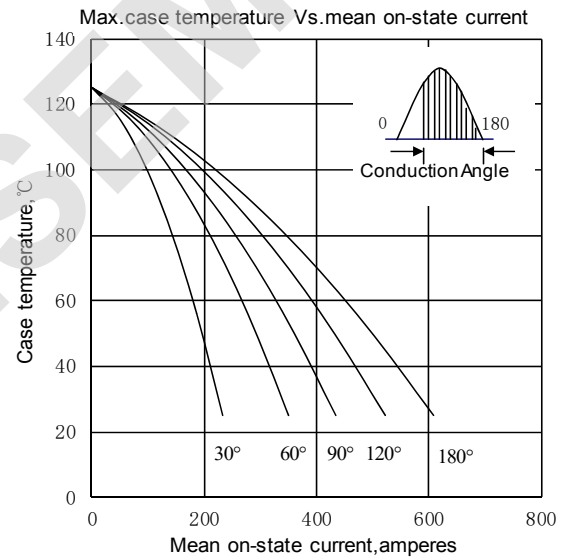


Fig.4

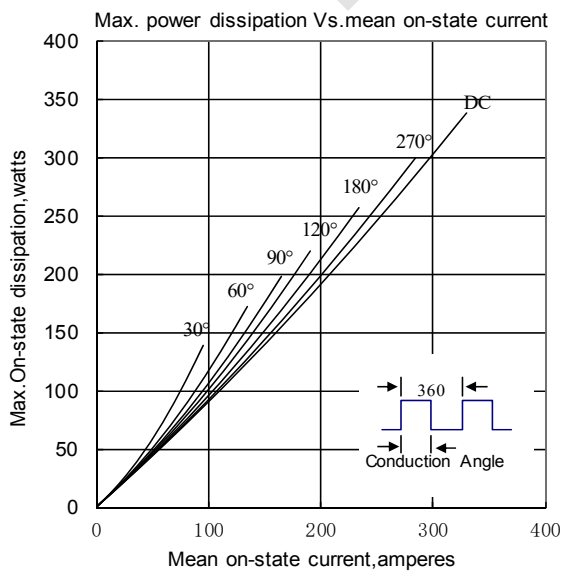


Fig.5

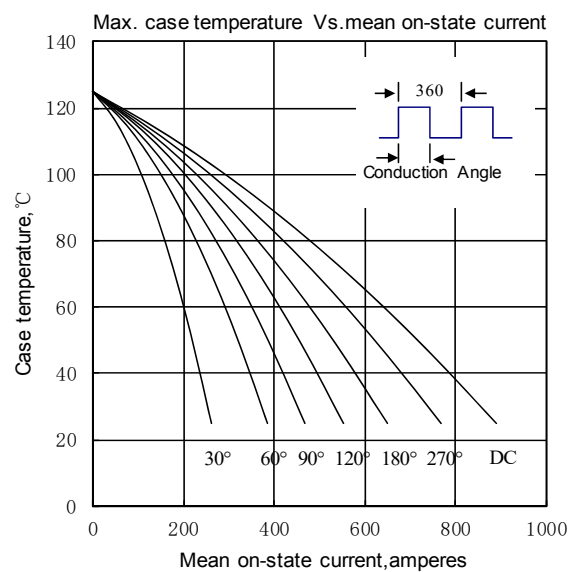


Fig.6

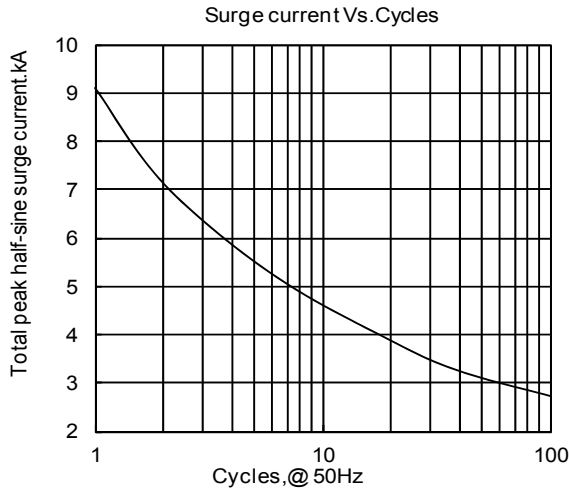


Fig 7

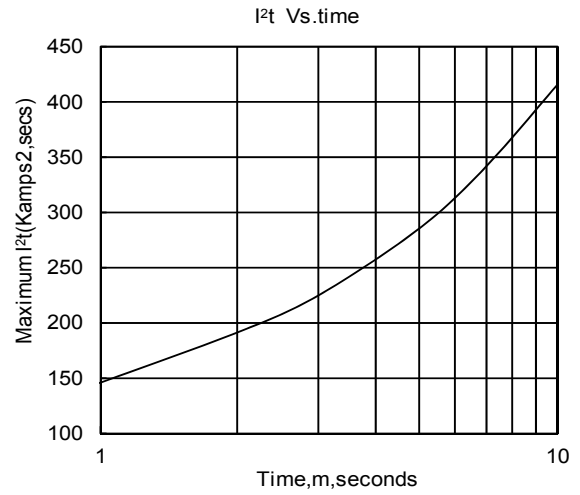


Fig 8

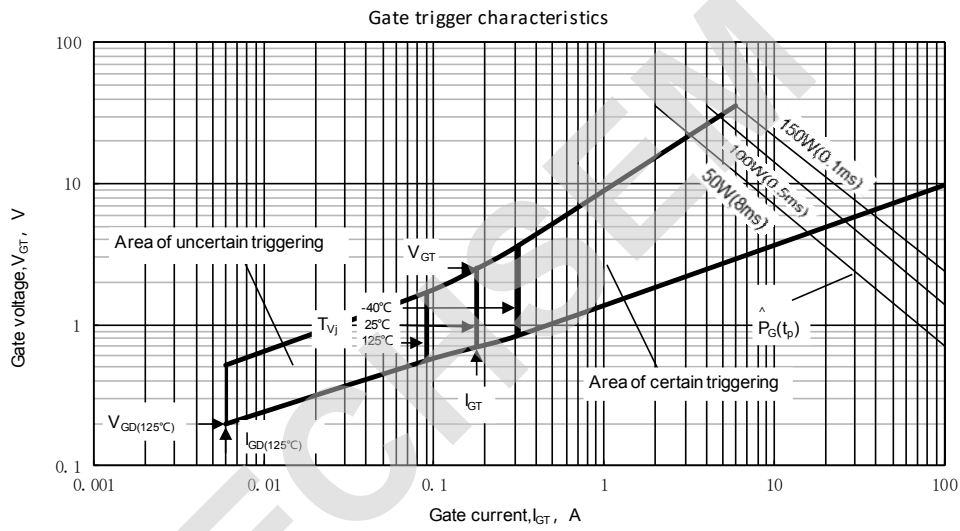
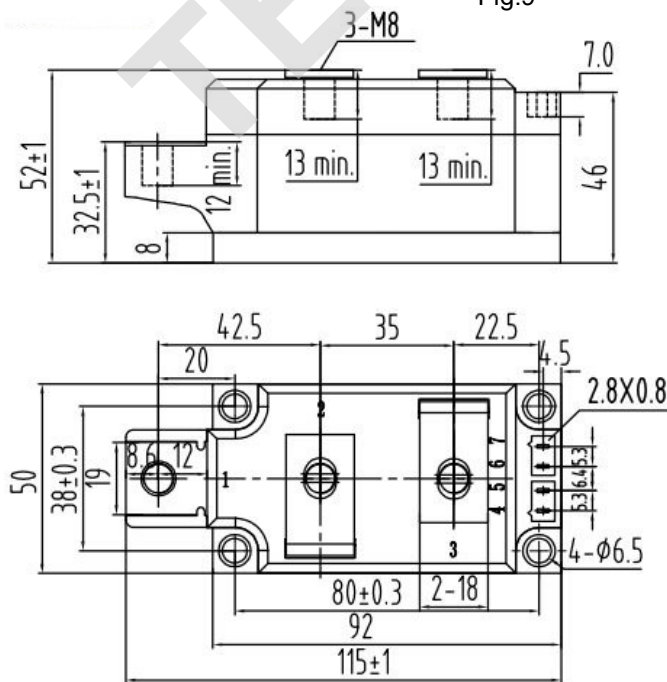
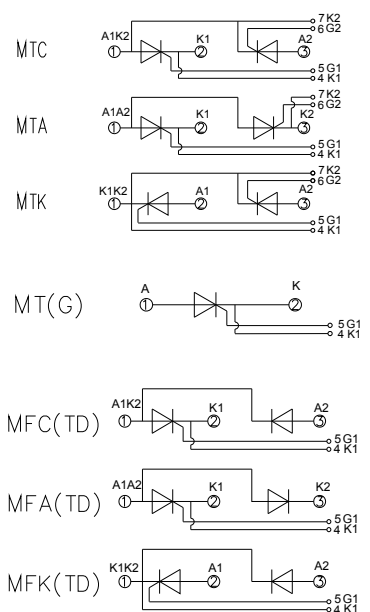


Fig 9

Outline:



Unmarked dimensional tolerance: ±0.5mm



TECHSEM reserves the right to change specifications without notice.